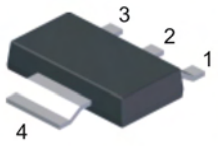
NEW PRODUCT

DZT953

PNP SURFACE MOUNT TRANSISTOR

Features

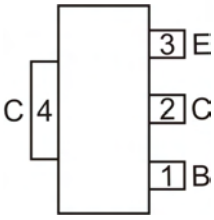
- Epitaxial Planar Die Construction
- Complementary NPN Type Available (DZT853)
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- **Lead Free By Design/RoHS Compliant (Note 1)**
- **"Green" Device (Note 2)**



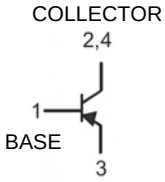
SOT-223

Mechanical Data

- Case: SOT-223
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish — Matte Tin annealed over Copper Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.115 grams (approximate)



TOP VIEW



Schematic and Pin Configuration

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-140	V
Collector-Emitter Voltage	V_{CEO}	-100	V
Emitter-Base Voltage	V_{EBO}	-6	V
Continuous Collector Current	I_C	-5	A
Peak Pulse Collector Current	I_{CM}	-10	A
Power Dissipation	P_D	1(Note 3) 3(Note 4)	W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	°C

Notes:
1. No purposefully added lead.
2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
3. Device mounted on FR-4 PCB, pad layout as shown on page 4.
4. The power which can be dissipated, assuming the device is mounted in a typical manner on a PCB with copper equal to 4 square inch minimum.

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Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-140	-165	—	V	I_C = -100μA, I_E = 0
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	-100	-120	—	V	I_C = -10mA*, I_B = 0
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-6	-9	—	V	I_E = -100μA, I_C = 0
Collector Cutoff Current	I_{CBO}	—	—	-50 -1	nA μA	V_{CB} = -100V, I_E = 0 V_{CB} = -100V, I_E = 0, T_A = 100°C
Emitter Cutoff Current	I_{EBO}	—	—	-10	nA	V_{EB} = - 6V, I_C = 0
ON CHARACTERISTICS						
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	— — — —	-18 -70 -125 -260	-50 -115 -220 -420	mV	I_C = -100mA, I_B = -10mA* I_C = -1A, I_B = -100mA* I_C = -2A, I_B = -200mA* I_C = -4A, I_B = -400mA*
Base-Emitter Saturation Voltage	$V_{BE(SAT)}$	—	-960	-1170	mV	I_C = -4A, I_B = -400mA*
Base-Emitter Turn-On Voltage	$V_{BE(ON)}$	—	-880	-1160	mV	I_{CE} = -4A, V_{CE} = -1V*
DC Current Gain	h_{FE}	100 100 50 30 —	220 200 100 70 15	— 300 — — —	—	I_C = -10mA, V_{CE} = -1V* I_C = -1A, V_{CE} = -1V* I_C = -3A, V_{CE} = -1V* I_C = -4A, V_{CE} = -1V* I_C = -10A, V_{CE} = -1V*
SMALL SIGNAL CHARACTERISTICS						
Current Gain-Bandwidth Product	f_T	—	125	—	MHz	I_C = -100mA, V_{CE} = -10V, f = 50MHz
Output Capacitance	C_{obo}	—	65	—	pF	V_{CB} = -10V, f = 1MHz
SWITCHING CHARACTERISTICS						
Switching Times	t_{on} t_{off}	—	65 100	—	ns	I_C = -2A, I_{B1} = -200mA I_{B2} = 200mA, V_{CC} = -10V

*Measured under pulsed conditions. Pulse width = 300μs. Duty cycle ≤2%

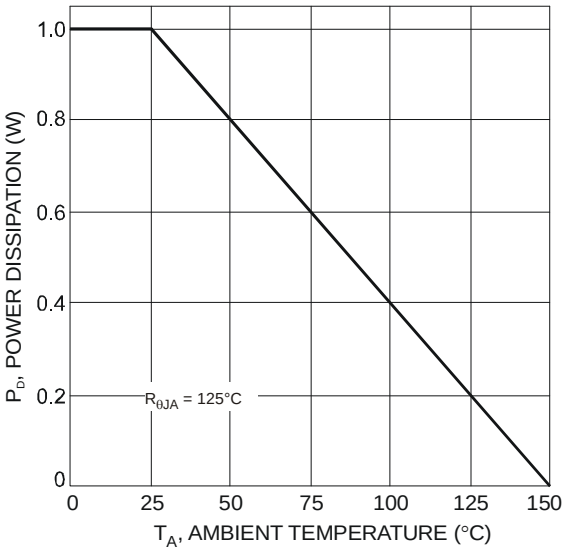


Fig. 1 Power Dissipation vs. Ambient Temperature (Note 3)

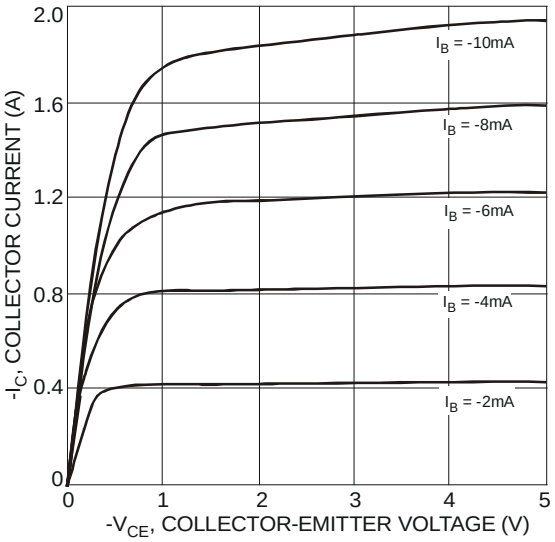


Fig 2. Collector Current vs. Collector Emitter Voltage

NEW PRODUCT

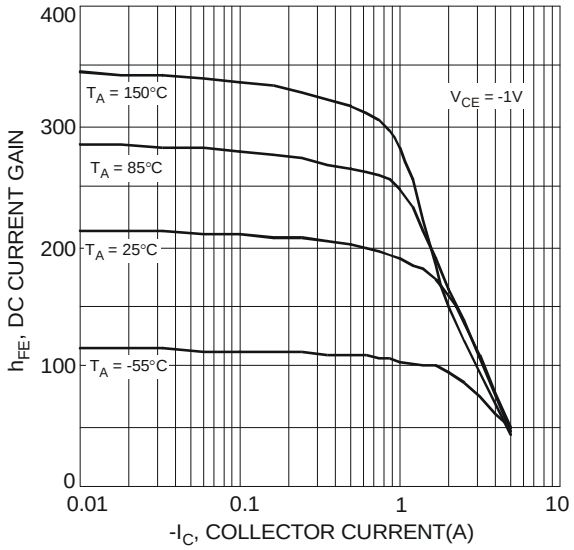


Fig. 3 Typical DC Current Gain vs. Collector Current

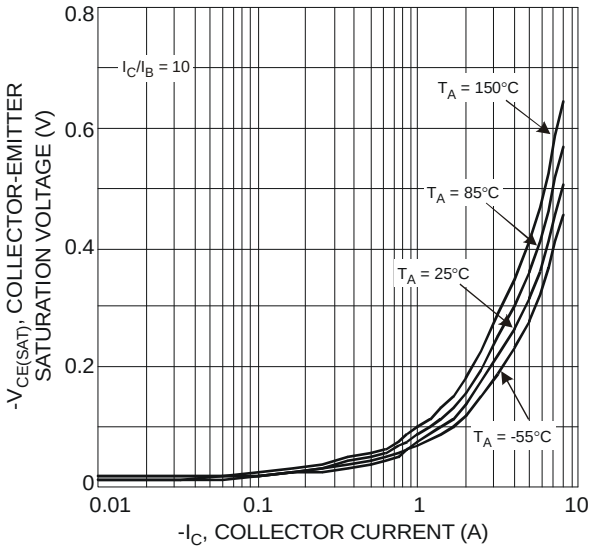


Fig. 4 Collector-Emitter Saturation Voltage vs. Collector Current

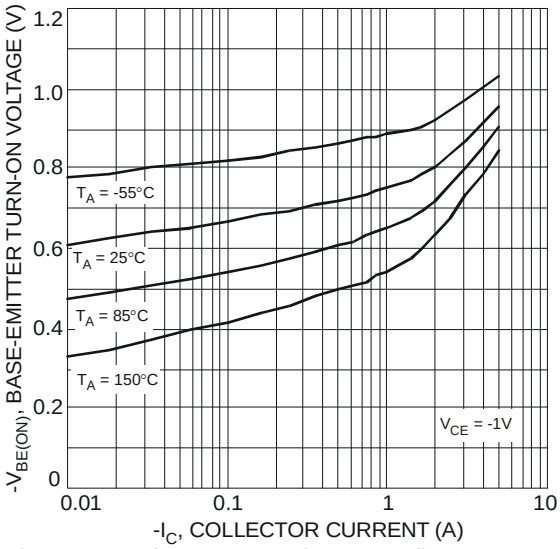


Fig. 5 Base-Emitter Turn-On Voltage vs. Collector Current

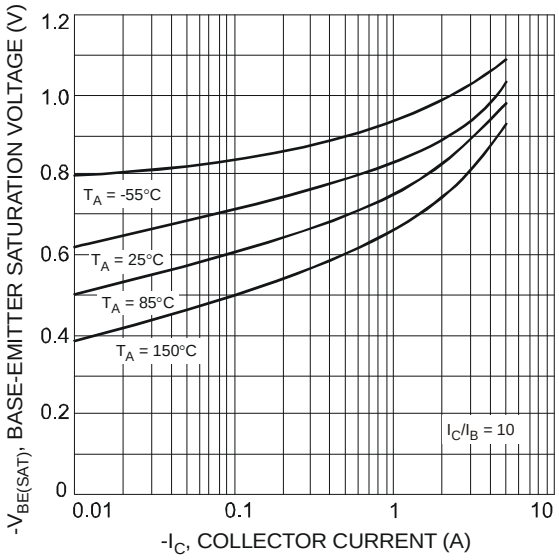


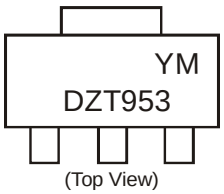
Fig. 6 Base-Emitter Saturation Voltage vs. Collector Current

Ordering Information (Note 5)

Device	Valid Marking Codes	Packaging	Shipping
DZT953-13	DZT953	SOT-223	2500/Tape & Reel
DZT953-13	PT06	SOT-223	2500/Tape & Reel

Notes: 5. Packaging Details as shown on page 4, or go to our website at http://www.diodes.com/ap2007.pdf.

Marking Information



(Top View)

DZT953 or PT06= Product Type Marking Code
YM = Date Code Marking
Y = Year ex: T = 2006
M = Month ex: 9 = September

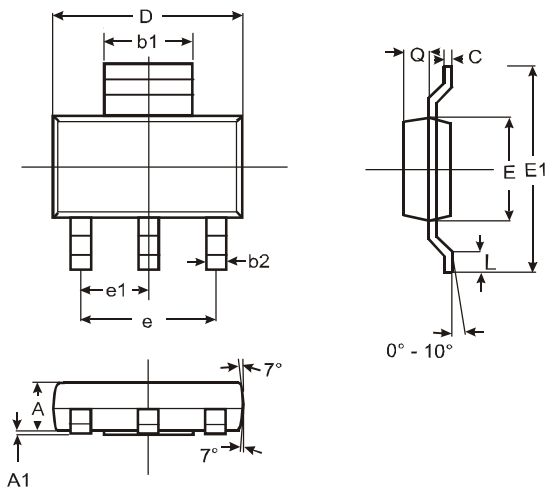
Date Code Key

Year	2006	2007	2008	2009	2010	2011	2012
Code	T	U	V	W	X	Y	Z

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

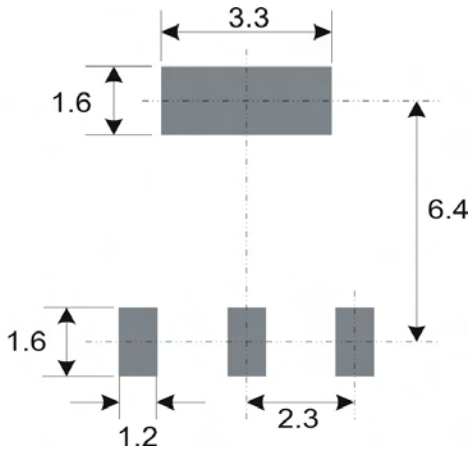
NEW PRODUCT

Package Outline Dimensions



SOT-223			
Dim	**Min**	**Max**	**Typ**
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b1	2.90	3.10	3.00
b2	0.60	0.80	0.70
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	—	—	4.60
e1	—	—	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89
All Dimensions in mm			

Suggested Pad Layout:



(Unit:mm)

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Diodes Incorporated:

DZT953-13